

2.0A GLASS PASSIVATED BRIDGE RECTIFIER

Reverse Voltage - 100 to 1000 V

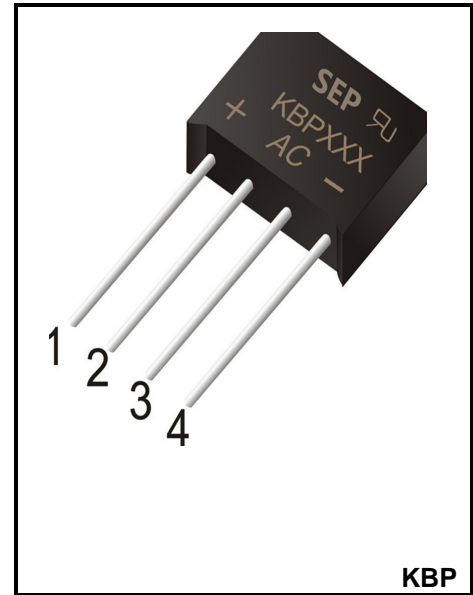
Forward Current – 2.0A

FEATURES

- ◆High current capability
- ◆Low forward voltage drop
- ◆Glass Passivated Chip Junction
- ◆Low power loss, high efficiency
- ◆Lead free in comply with EU RoHS 2011/65/EU directives

MECHANICAL DATA

- ◆Case: KBP
- ◆Terminals: Solderable per MIL-STD-202, Method 208
- ◆Approx. Weight: 0.33g / 0.012oz



Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter	Symbols	KBP201	KBP202	KBP204	KBP206	KBP208	KBP210	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	100	200	400	600	800	1000	V
Average Rectified Output Current	$I_{(AV)}$	2						A
Peak Forward Surge Current 8.3 ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	60						A
Forward Voltage per element @ $I_F=2.0A$ and 25°C	V_F	1.1						V
Maximum DC Reverse Current @ $T_j=25^\circ C$ at Rated DC Blocking Voltage @ $T_j=125^\circ C$	I_R	10 500						μA
Typical Junction Capacitance ^(Note1)	C_j	25						pF
Typical Thermal Resistance ^(Note2)	$R_{\theta JA}$ $R_{\theta JC}$	30/11						°C/W
Operating and Storage Temperature Range	T_j , T_{stg}	-55 ~ +150						°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) Thermal Resistance Junction to Case, Lead and Ambient.

RATINGS AND CHARACTERISTIC CURVES

FIG.1- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER BRIDGE ELEMENT

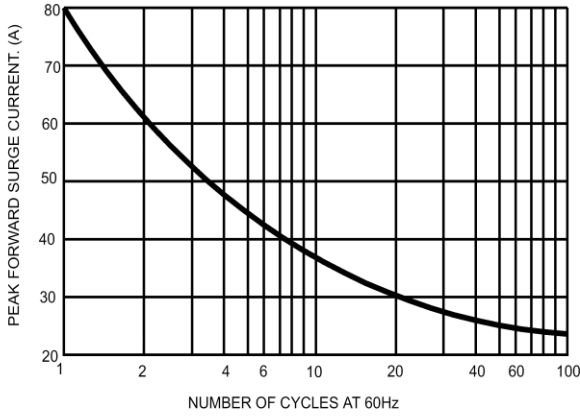


Fig.2 Average Rectified Output Current Derating Curve

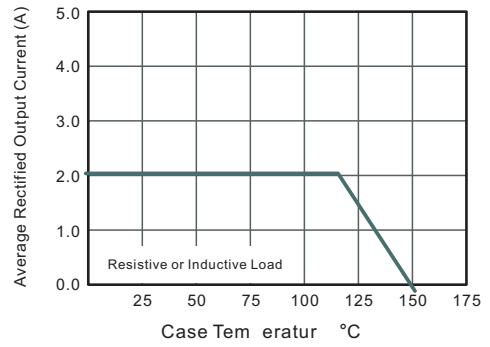


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER BRIDGE ELEMENT

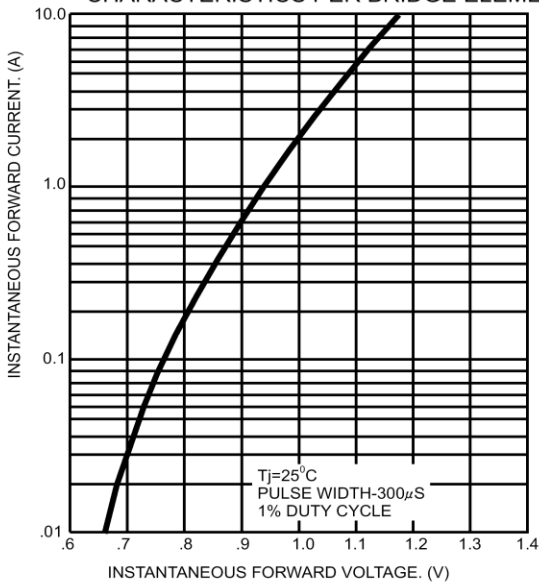
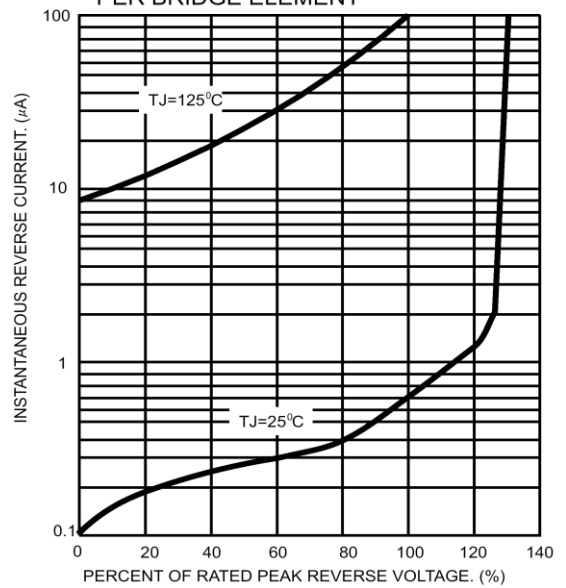


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER BRIDGE ELEMENT



单击下面可查看定价，库存，交付和生命周期等信息

[>>YFW\(佑风微\)](#)